

RJK0391DPA

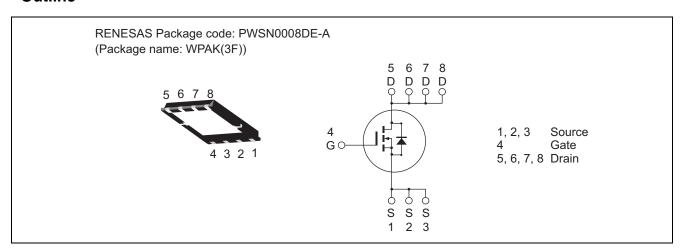
30V, 50A, 2.9m Ω max. N Channel Power MOS FET High Speed Power Switching

R07DS0923EJ0400 Rev.4.00 Mar 21, 2013

Features

- High speed switching
- Capable of 4.5 V gate drive
- Low drive current
- High density mounting
- Low on-resistance
- Pb-free
- Halogen-free

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item	Symbol	Ratings	Unit
Drain to source voltage	V _{DSS}	30	V
Gate to source voltage	V_{GSS}	±20	V
Drain current	I _D	50	A
Drain peak current	I _{D(pulse)} Note1	200	A
Body-drain diode reverse drain current	I _{DR}	50	A
Avalanche current	I _{AP} Note 2	25	A
Avalanche energy	E _{AR} Note 2	62.5	mJ
Channel dissipation	Pch Note3	50	W
Channel to case thermal impedance	θch-c Note3	2.5	°C/W
Channel temperature	Tch	150	°C
Storage temperature	Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

- 2. Value at Tch = 25°C, Rg \geq 50 Ω
- 3. $Tc = 25^{\circ}C$

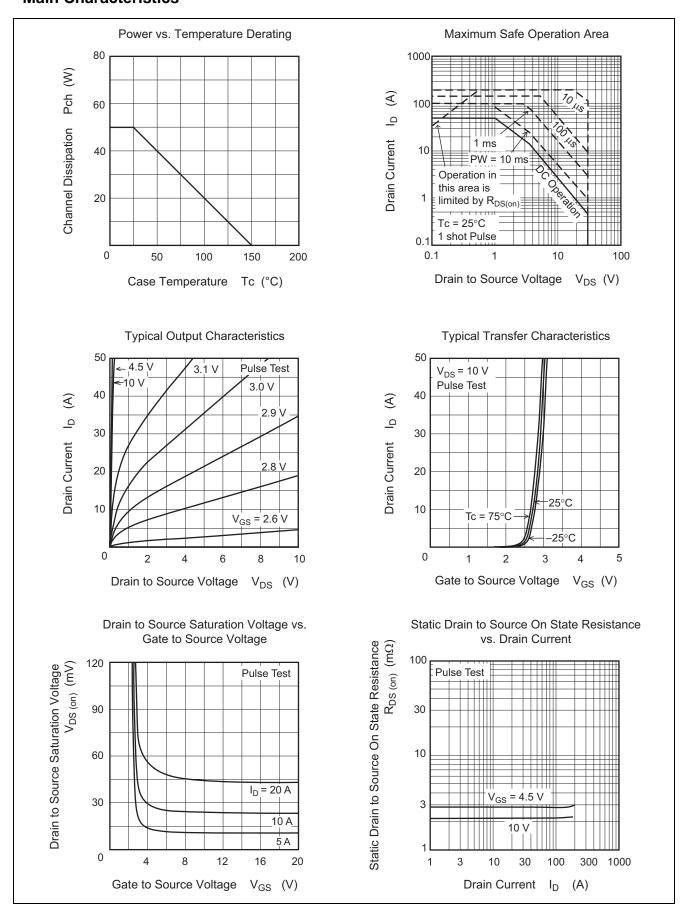
Electrical Characteristics

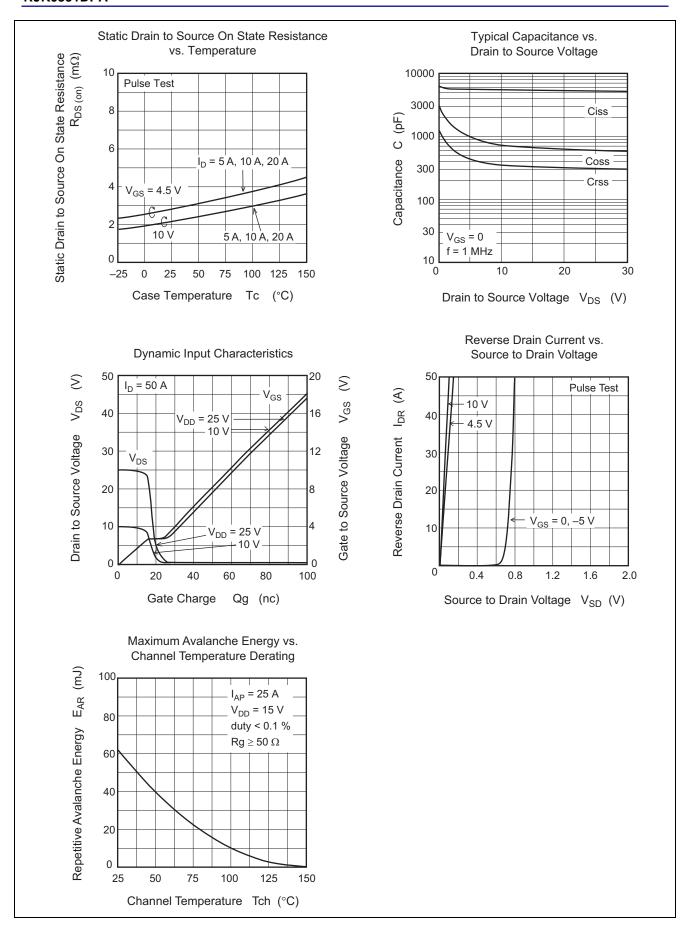
 $(Ta = 25^{\circ}C)$

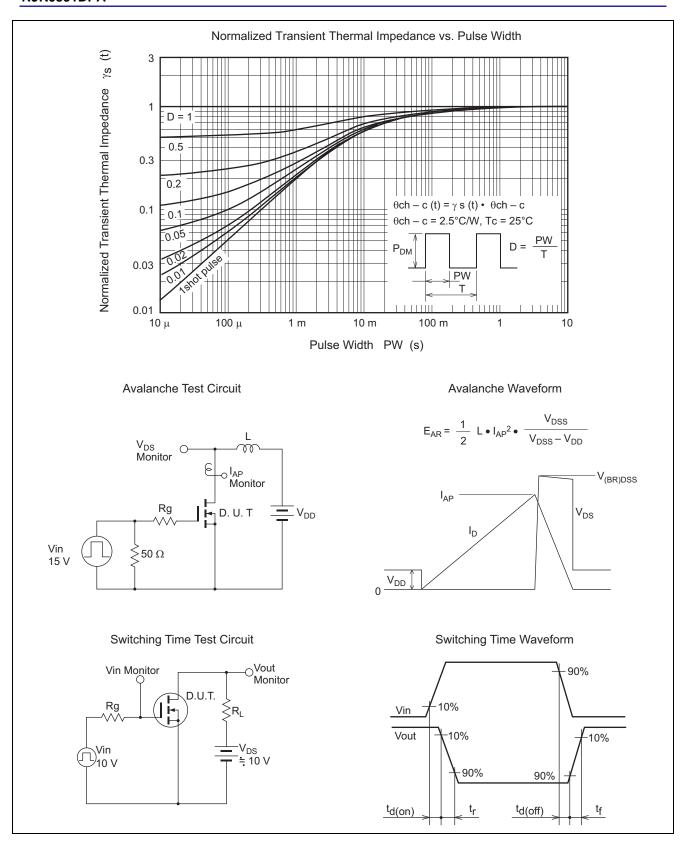
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Drain to source breakdown voltage	$V_{(BR)DSS}$	30	_	_	V	$I_D = 10 \text{ mA}, V_{GS} = 0$
Gate to source leak current	I_{GSS}	_	_	± 0.5	μΑ	$V_{GS} = \pm 20 \text{ V}, V_{DS} = 0$
Zero gate voltage drain current	I _{DSS}	_	_	1	μΑ	$V_{DS} = 30 \text{ V}, V_{GS} = 0$
Gate to source cutoff voltage	$V_{GS(off)}$	1.2	_	2.5	V	$V_{DS} = 10 \text{ V}, I_D = 1 \text{ mA}$
Static drain to source on state	R _{DS(on)}	_	2.2	2.9	mΩ	$I_D = 25 \text{ A}, V_{GS} = 10 \text{ V}^{\text{Note4}}$
resistance	R _{DS(on)}	_	2.8	3.9	mΩ	$I_D = 25 \text{ A}, V_{GS} = 4.5 \text{ V}^{\text{Note4}}$
Forward transfer admittance	y _{fs}	_	160	_	S	$I_D = 25 \text{ A}, V_{DS} = 10 \text{ V}^{\text{Note4}}$
Input capacitance	Ciss	_	5600	_	pF	V _{DS} = 10 V
Output capacitance	Coss	_	710	_	pF	$V_{GS} = 0$
Reverse transfer capacitance	Crss	_	370	_	pF	f = 1 MHz
Gate Resistance	Rg	_	0.95	_	Ω	
Total gate charge	Qg	_	34	_	nC	V _{DD} = 10 V V _{GS} = 4.5 V I _D = 50 A
Gate to source charge	Qgs	_	16	_	nC	
Gate to drain charge	Qgd	_	7.4	_	nC	
Turn-on delay time	t _{d(on)}	_	15.3	_	ns	$V_{GS} = 10 \text{ V}, I_D = 25 \text{ A}$
Rise time	t _r	_	8	_	ns	$V_{DD} \cong 10 \text{ V}$
Turn-off delay time	$t_{d(off)}$		66	_	ns	$R_L = 0.4 \Omega$
Fall time	t _f		14.1	_	ns	$Rg = 4.7 \Omega$
Body-drain diode forward voltage	V_{DF}		0.80	1.04	V	$I_F = 50 \text{ A}, V_{GS} = 0^{\text{Note4}}$
Body-drain diode reverse recovery	t _{rr}	_	35	_	ns	$I_F = 50 \text{ A}, V_{GS} = 0$
time						$di_F/dt = 100 A/ \mu s$

Notes: 4. Pulse test

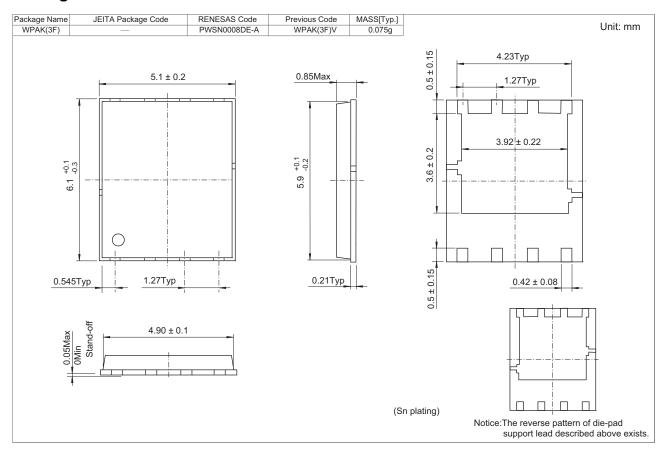
Main Characteristics







Package Dimensions



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJK0391DPA-00-J5A	3000 pcs	Taping

Note: The symbol of 2nd "-" is occasionally presented as "#".

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